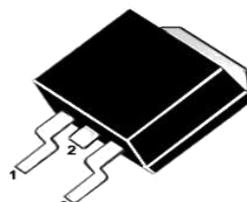
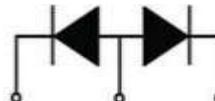


MUR1610CTR-MUR1660CTR	TO-263   
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Absolute Maximum Ratings (Ta=25°C unless otherwise noted)

Parameter	Symbol	MUR 1610 CTR	MUR 1615 CTR	MUR 1620 CTR	MUR 1640 CTR	MUR 1660 CTR	Unit
Peak Repetitive Reverse Voltage	V _{RRM}	100	150	200	400	600	V
Working Peak Reverse Voltage	V _{RWM}	70	105	140	280	420	V
DC Blocking Voltage	V _{R(DC)}	100	150	200	400	600	V
Average Rectified Forward Current Per Leg Total Device	I _{F(AV)}			8 16			A
Peak Rectified Forward Current Per Diode Leg (Rated VR, Square Wave, 20 kHz)	I _{FM}			16			A
Nonrepetitive Peak Surge Current(Surge applied at rated load conditions half wave, single phase, 60 Hz)	I _{FSM}		1.Cathode 2.Anode 3.Cathode	180			A
Operating Junction Temperature and Storage Temperature	T _J , T _{Stg}			-55 to +150			°C
Maximum Thermal Resistance, Junction-to-Case(Per Leg)	R _{θJC}		3.0		2.0		°C/W

ELECTRICAL CHARACTERISTICS (Per Diode Leg)

Parameter	Symbol	MUR 1610 CTR	MUR 1615 CTR	MUR 1620 CTR	MUR 1640 CTR	MUR 1660 CTR	Unit
Forward Voltage (Note 1)(I _F = 8.0 A, T _C = 25°C)	V _F		1.0		1.3	1.7	V
Maximum Instantaneous Reverse Current (Note 1) (Rated DC Voltage, T _C = 125°C) (Rated DC Voltage, T _C = 25°C)	I _R	250 10		500 10			μ A
Maximum Reverse Recovery Time (I _F = 0.5 A, I _R = 1.0 A, I _{REC} = 0.25 A)	T _{RR}		35		35		ns

Note 1.Pulse Test: Pulse Width = 300 μs, Duty Cycle ≤2.0%

Typical Characteristics

FIG1: IF (AV) -Tc Derating

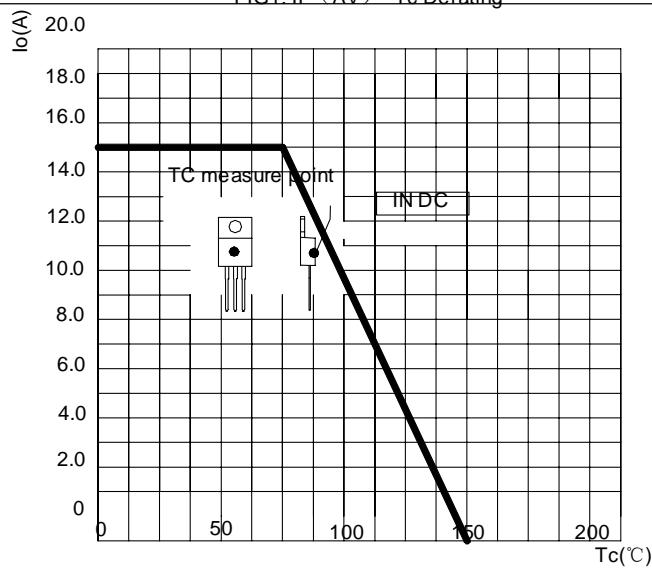


FIG2: Surge Forward Current Capability

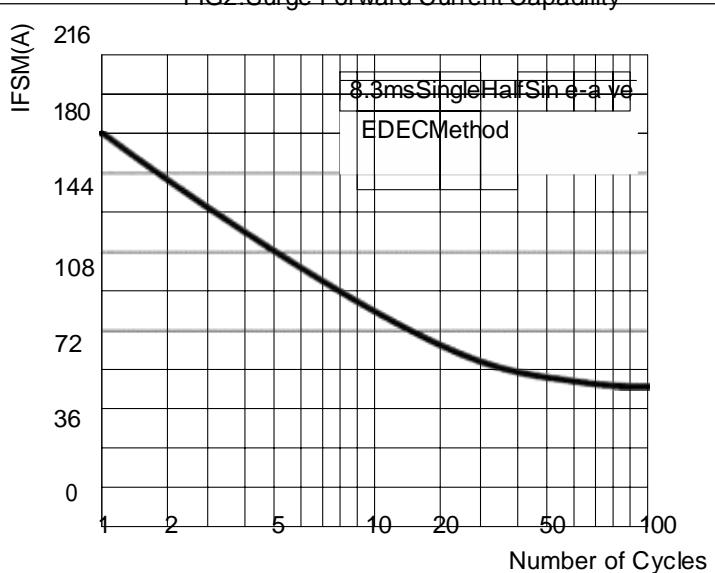


FIG3: Instantaneous Forward Voltage

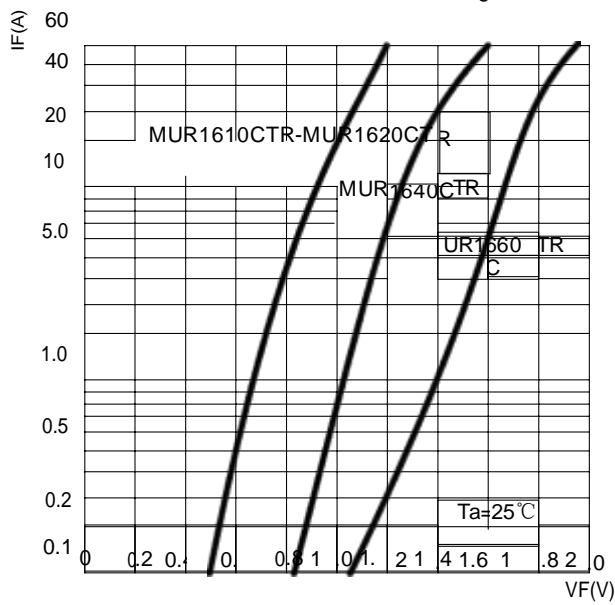


FIG4: Typical Reverse Characteristics

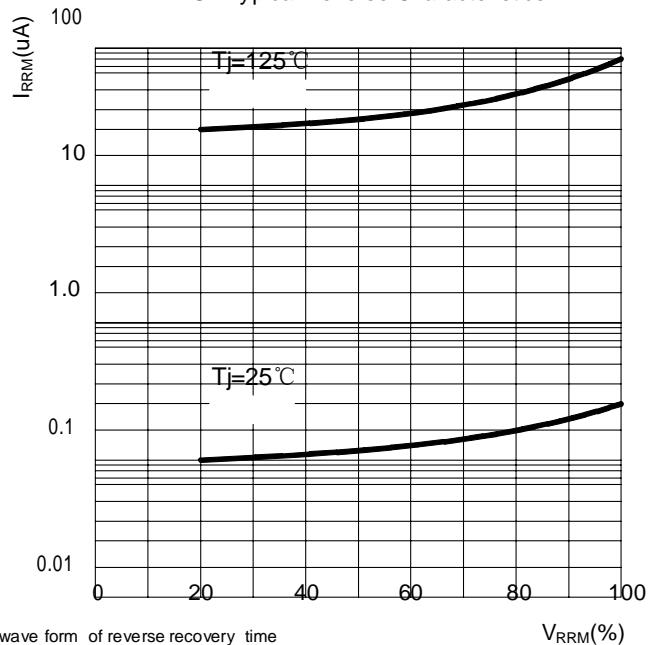


FIG.5: Diagram of circuit and Testing wave form of reverse recovery time

